



REVISION HISTORY

<u>Revision</u>	<u>Description</u>	<u>Issue Date</u>
Rev. 1.0	Initial Issue	Jul.25.2004
Rev. 2.0	Revised $I_{SB(max)}$: 0.5mA => 1.25mA	May.11.2006
Rev. 2.1	Revised Package Outline Dimension(TSOP-II)	Apr.12.2007
Rev. 2.2	Deleted L Spec. Added SL Spec. Revised Test Condition of $I_{CC}/I_{SB1}/I_{DR}$ Revised V_{TERM} to V_{T1} and V_{T2}	Nov.8.2007
Rev. 2.3	Revised I_{DR}	Mar.21.2008
Rev. 2.4	Added I_{SB1}/I_{DR} values when $T_A = 25^\circ C$ and $T_A = 40^\circ C$ Revised FEATURES & ORDERING INFORMATION Lead free and green package available to Green package available Added packing type in ORDERING INFORMATION Deleted T_{SOLDER} in ABSOLUTE MAXIMUM RATINGS	Mar.30.2009
Rev. 2.5	Revised PACKAGE OUTLINE DIMENSION in page 10	May.6.2010
Rev. 2.6	Revised ORDERING INFORMATION in page 11	Aug.30.2010
Rev. 2.7	Revised Notes of READ CYCLE of TIMING WAVEFORMS in page 5	Jan.7.2016
Rev. 2.8	Corrected ORDERING INFORMATION Typo.	May.20.2016
Rev. 2.9	Deleted WRITE CYCLE Notes : 1. WE#,CE#, LB#, UB# must be high during all address transitions. in page 7	Jun.29.2016
Rev. 2.10	Revised $t_{WP(min)}$ in AC ELECTRICAL CHARACTERISTICS	Sep.11.2017
Rev. 3.0	1. Deleted FEATURES Standby current : 1 μ A (TYP.) SL-version--Page 1 2. Deleted PRODUCT FAMILY Standby(I_{SB1} ,TYP.) : 1 μ A(SL) --- Page 1 3. Deleted DC ELECTRICAL CHARACTERISTICS : Standby Power Supply Current : I_{SB1} --- Page4 4. Deleted DC ELECTRICAL CHARACTERISTICS : Notes: 5 --- Page 4 5. Deleted DATA RETENTION CHARACTERISTICS : Data Retention Current: I_{DR} --- Page 9 6. Revised ORDERING INFORMATION in Page 12~Page15	Jun.18.2024

FEATURES

- Fast access time : 45/55/70ns
- Low power consumption:
Operating current : 40/30/20mA (TYP.)
Standby current : 2 μ A (TYP.) LL-version
- Single 2.7V ~ 3.6V power supply
- All inputs and outputs TTL compatible
- Fully static operation
- Tri-state output
- Data byte control : LB# (DQ0 ~ DQ7)
UB# (DQ8 ~ DQ15)
- Data retention voltage : 1.5V (MIN.)
- **Green package available**
- Package : 44-pin 400mil TSOP II
48-ball 6mm x 8mm TFBGA

GENERAL DESCRIPTION

The LY62L25616 is a 4,194,304-bit low power CMOS static random access memory organized as 262,144 words by 16 bits. It is fabricated using very high performance, high reliability CMOS technology. Its standby current is stable within the range of operating temperature.

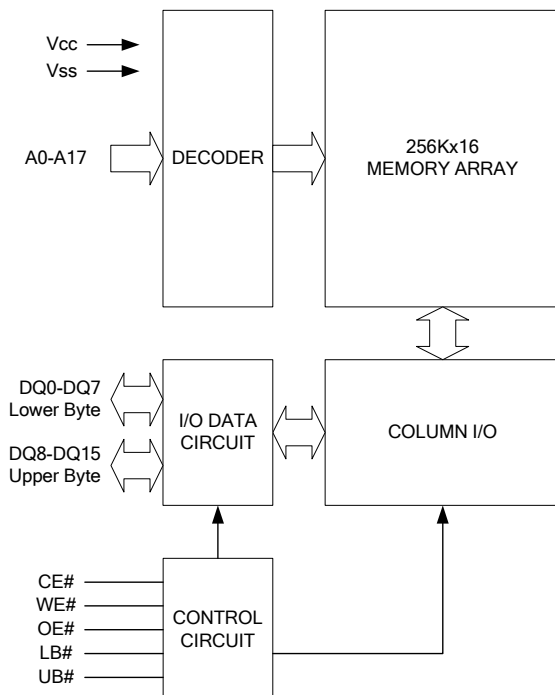
The LY62L25616 is well designed for low power application, and particularly well suited for battery back-up nonvolatile memory application.

The LY62L25616 operates from a single power supply of 2.7V ~ 3.6V and all inputs and outputs are fully TTL compatible

PRODUCT FAMILY

Product Family	Operating Temperature	V _{CC} Range	Speed	Power Dissipation	
				Standby(I _{SB1} , TYP.)	Operating(I _{CC} , TYP.)
LY62L25616	0 ~ 70°C	2.7 ~ 3.6V	45/55/70ns	2 μ A(LL)	40/30/20mA
LY62L25616(E)	-20 ~ 80°C	2.7 ~ 3.6V	45/55/70ns	2 μ A(LL)	40/30/20mA
LY62L25616(I)	-40 ~ 85°C	2.7 ~ 3.6V	45/55/70ns	2 μ A(LL)	40/30/20mA

FUNCTIONAL BLOCK DIAGRAM

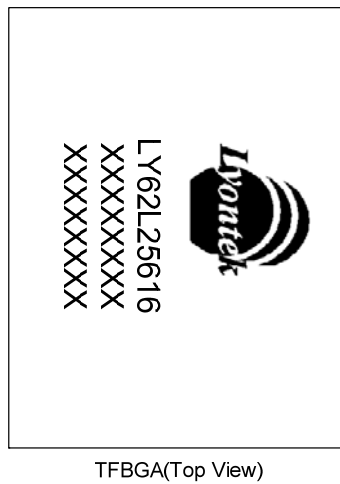
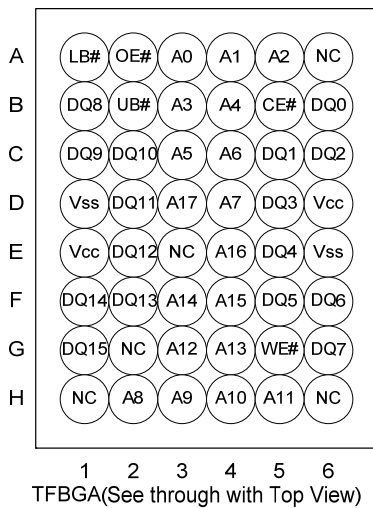
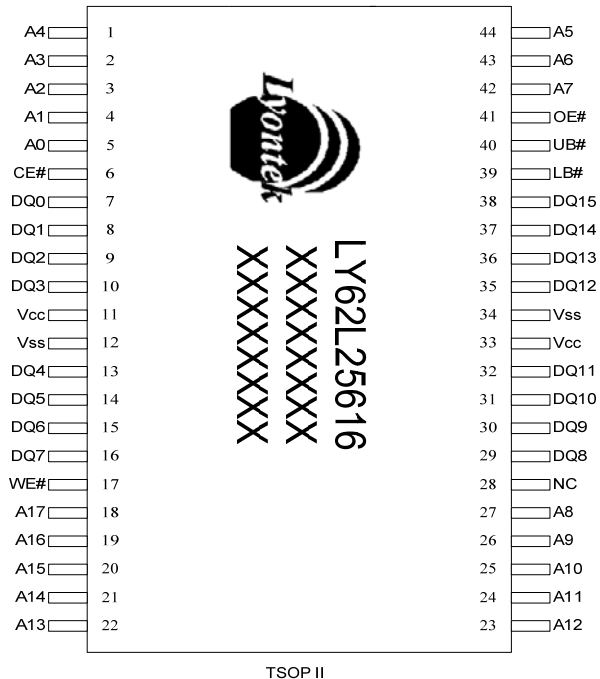


PIN DESCRIPTION

SYMBOL	DESCRIPTION
A0 - A17	Address Inputs
DQ0 - DQ15	Data Inputs/Outputs
CE#	Chip Enable Input
WE#	Write Enable Input
OE#	Output Enable Input
LB#	Lower Byte Control
UB#	Upper Byte Control
V _{CC}	Power Supply
V _{SS}	Ground



PIN CONFIGURATION





ABSOLUTE MAXIMUM RATINGS*

PARAMETER	SYMBOL	RATING	UNIT
Voltage on V _{CC} relative to V _{SS}	V _{T1}	-0.5 to 4.6	V
Voltage on any other pin relative to V _{SS}	V _{T2}	-0.5 to V _{CC} +0.5	V
Operating Temperature	T _A	0 to 70(C grade)	°C
		-20 to 80(E grade)	
		-40 to 85(I grade)	
Storage Temperature	T _{STG}	-65 to 150	°C
Power Dissipation	P _D	1	W
DC Output Current	I _{OUT}	50	mA

*Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to the absolute maximum rating conditions for extended period may affect device reliability.

TRUTH TABLE

MODE	CE#	OE#	WE#	LB#	UB#	I/O OPERATION		SUPPLY CURRENT
						DQ0 - DQ7	DQ8 - DQ15	
Standby	H	X	X	X	X	High-Z	High-Z	I _{SB} , I _{SB1}
	X	X	X	H	H	High-Z	High-Z	
Output Disable	L	H	H	L	X	High-Z	High-Z	I _{CC} , I _{CC1}
	L	H	H	X	L	High-Z	High-Z	
Read	L	L	H	L	H	D _{OUT}	High-Z	I _{CC} , I _{CC1}
	L	L	H	H	L	High-Z	D _{OUT}	
	L	L	H	L	L	D _{OUT}	D _{OUT}	
Write	L	X	L	L	H	D _{IN}	High-Z	I _{CC} , I _{CC1}
	L	X	L	H	L	High-Z	D _{IN}	
	L	X	L	L	L	D _{IN}	D _{IN}	

Note: H = V_{IH}, L = V_{IL}, X = Don't care.



DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP. ^{*4}	MAX.	UNIT	
Supply Voltage	V _{CC}		2.7	3.0	3.6	V	
Input High Voltage	V _{IH} ^{*1}		2.2	-	V _{CC} +0.3	V	
Input Low Voltage	V _{IL} ^{*2}		- 0.2	-	0.6	V	
Input Leakage Current	I _{LI}	V _{CC} ≥ V _{IN} ≥ V _{SS}	- 1	-	1	μA	
Output Leakage Current	I _{LO}	V _{CC} ≥ V _{OUT} ≥ V _{SS} , Output Disabled	- 1	-	1	μA	
Output High Voltage	V _{OH}	I _{OH} = -1mA	2.2	2.7	-	V	
Output Low Voltage	V _{OL}	I _{OL} = 2mA	-	-	0.4	V	
Average Operating Power supply Current	I _{CC}	Cycle time = MIN. CE# = V _{IL} , I _{I/O} = 0mA Other pins at V _{IL} or V _{IH}	- 45	-	40	50	mA
			- 55	-	30	40	mA
			- 70	-	20	30	mA
	I _{CC1}	Cycle time = 1μs CE# = 0.2V , I _{I/O} = 0mA Other pins at 0.2V or V _{CC} - 0.2V	-	4	5	mA	
Standby Power Supply Current	I _{SB}	CE# = V _{IH} , other pins at V _{IL} or V _{IH}	-	0.3	1.25	mA	
	I _{SB1}	CE# ≥ V _{CC} - 0.2V Others at 0.2V or V _{CC} - 0.2V	LL	-	2	15	μA
			LLE/LLI	-	2	20	μA

Notes:

1. V_{IH}(max) = V_{CC} + 3.0V for pulse width less than 10ns.
2. V_{IL}(min) = V_{SS} - 3.0V for pulse width less than 10ns.
3. Over/Undershoot specifications are characterized, not 100% tested.
4. Typical values are included for reference only and are not guaranteed or tested.
Typical values are measured at V_{CC} = V_{CC}(TYP.) and T_A = 25°C

**CAPACITANCE ($T_A = 25^\circ\text{C}$, $f = 1.0\text{MHz}$)**

PARAMETER	SYMBOL	MIN.	MAX.	UNIT
Input Capacitance	C_{IN}	-	6	pF
Input/ Output Capacitance	$C_{I/O}$	-	8	pF

Note : These parameters are guaranteed by device characterization, but not production tested.

AC TEST CONDITIONS

Input Pulse Levels	0.2V to $V_{CC} - 0.2V$
Input Rise and Fall Times	3ns
Input and Output Timing Reference Levels	1.5V
Output Load	$C_L = 30\text{pF} + 1\text{TTL}$, $I_{OH}/I_{OL} = -1\text{mA}/2\text{mA}$

AC ELECTRICAL CHARACTERISTICS**(1) READ CYCLE**

PARAMETER	SYM.	LY62L25616-45		LY62L25616-55		LY62L25616-70		UNIT
		MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
Read Cycle Time	t_{RC}	45	-	55	-	70	-	ns
Address Access Time	t_{AA}	-	45	-	55	-	70	ns
Chip Enable Access Time	t_{ACE}	-	45	-	55	-	70	ns
Output Enable Access Time	t_{OE}	-	25	-	30	-	35	ns
Chip Enable to Output in Low-Z	t_{CLZ}^*	10	-	10	-	10	-	ns
Output Enable to Output in Low-Z	t_{OLZ}^*	5	-	5	-	5	-	ns
Chip Disable to Output in High-Z	t_{CHZ}^*	-	15	-	20	-	25	ns
Output Disable to Output in High-Z	t_{OHZ}^*	-	15	-	20	-	25	ns
Output Hold from Address Change	t_{OH}	10	-	10	-	10	-	ns
LB#, UB# Access Time	t_{BA}	-	45	-	55	-	70	ns
LB#, UB# to High-Z Output	t_{BHZ}^*	-	20	-	25	-	30	ns
LB#, UB# to Low-Z Output	t_{BLZ}^*	10	-	10	-	10	-	ns

(2) WRITE CYCLE

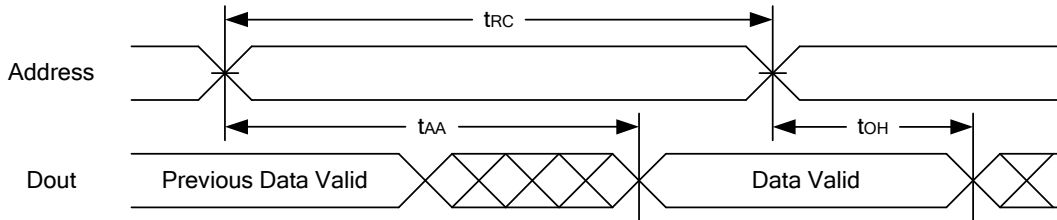
PARAMETER	SYM.	LY62L25616-45		LY62L25616-55		LY62L25616-70		UNIT
		MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
Write Cycle Time	t_{WC}	45	-	55	-	70	-	ns
Address Valid to End of Write	t_{AW}	40	-	50	-	60	-	ns
Chip Enable to End of Write	t_{CW}	40	-	50	-	60	-	ns
Address Set-up Time	t_{AS}	0	-	0	-	0	-	ns
Write Pulse Width	t_{WP}	30	-	35	-	45	-	ns
Write Recovery Time	t_{WR}	0	-	0	-	0	-	ns
Data to Write Time Overlap	t_{DW}	20	-	25	-	30	-	ns
Data Hold from End of Write Time	t_{DH}	0	-	0	-	0	-	ns
Output Active from End of Write	t_{OW}^*	5	-	5	-	5	-	ns
Write to Output in High-Z	t_{WHZ}^*	-	15	-	20	-	25	ns
LB#, UB# Valid to End of Write	t_{BW}	35	-	45	-	60	-	ns

*These parameters are guaranteed by device characterization, but not production tested.

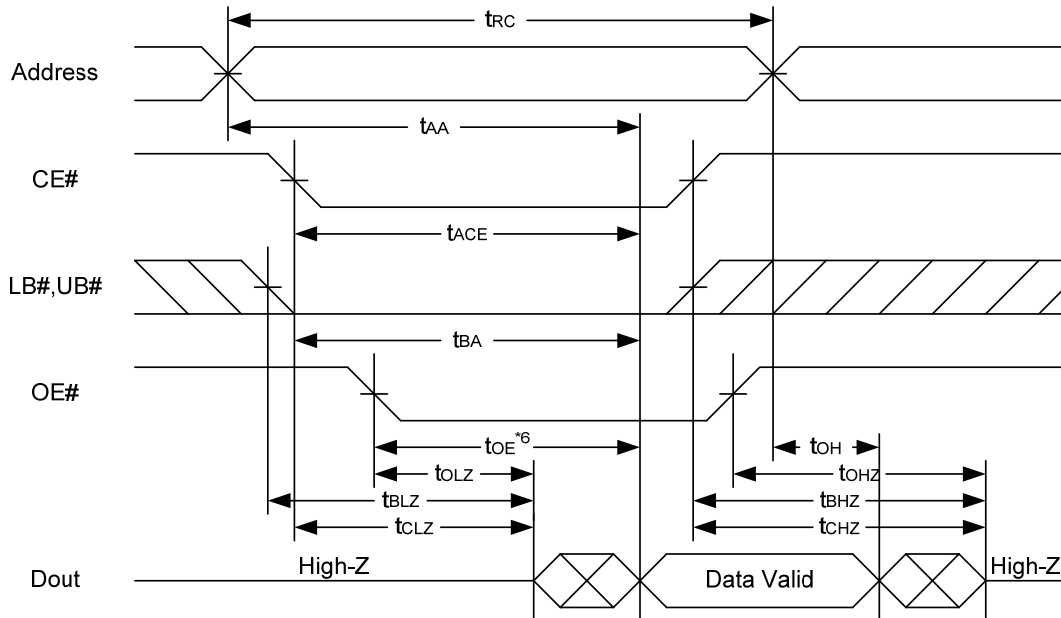


TIMING WAVEFORMS

READ CYCLE 1 (Address Controlled) (1,2)



READ CYCLE 2 (CE# and OE# Controlled) (1,3,4,5)

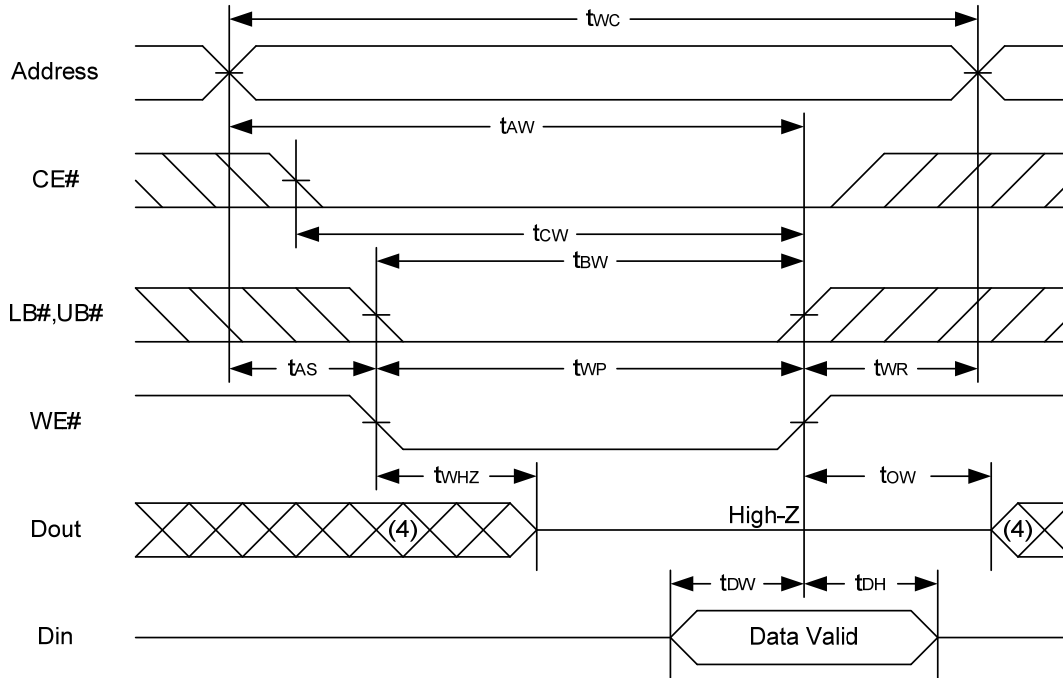


Notes :

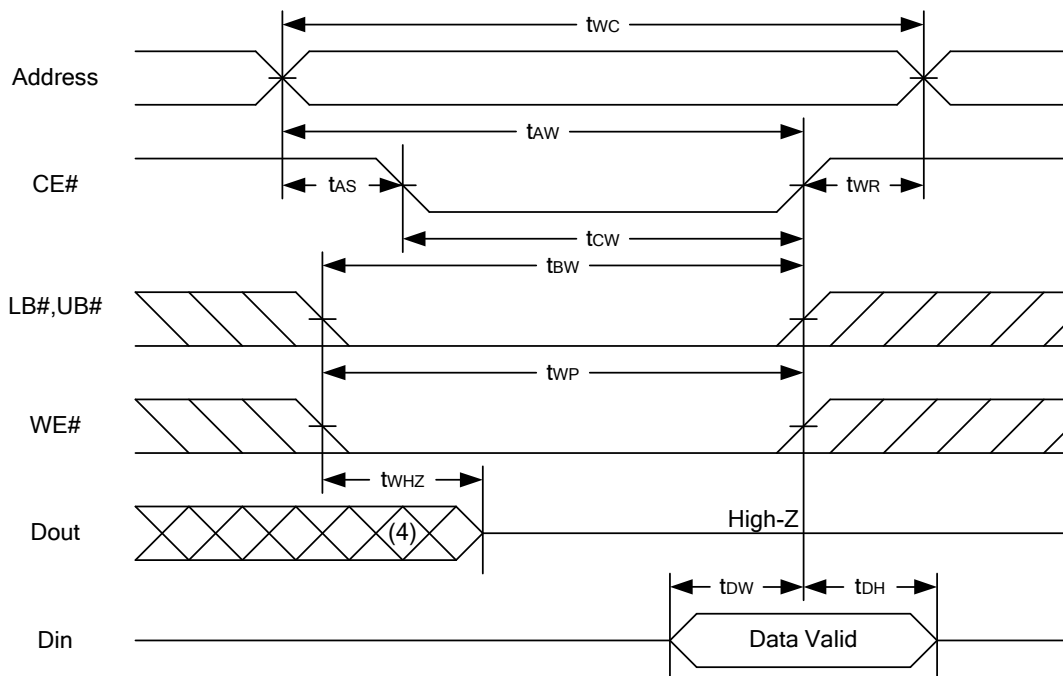
1. WE# is high for read cycle.
2. Device is continuously selected OE# = low, CE# = low, LB# or UB# = low.
3. Address must be valid prior to or coincident with CE# = low, LB# or UB# = low transition; otherwise t_{AA} is the limiting parameter.
4. t_{CLZ} , t_{BLZ} , t_{OLZ} , t_{CHZ} , t_{BHZ} and t_{OHZ} are specified with $C_L = 5pF$. Transition is measured $\pm 500mV$ from steady state.
5. At any given temperature and voltage condition, t_{CHZ} is less than t_{CLZ} , t_{BHZ} is less than t_{BLZ} , t_{OHZ} is less than t_{OLZ} .
6. CE# = low, LB# or UB# = low transition must be at least 25ns prior to OE# = low transition; otherwise t_{BA} is the limiting parameter.



WRITE CYCLE 1 (WE# Controlled) (1,2,4,5)

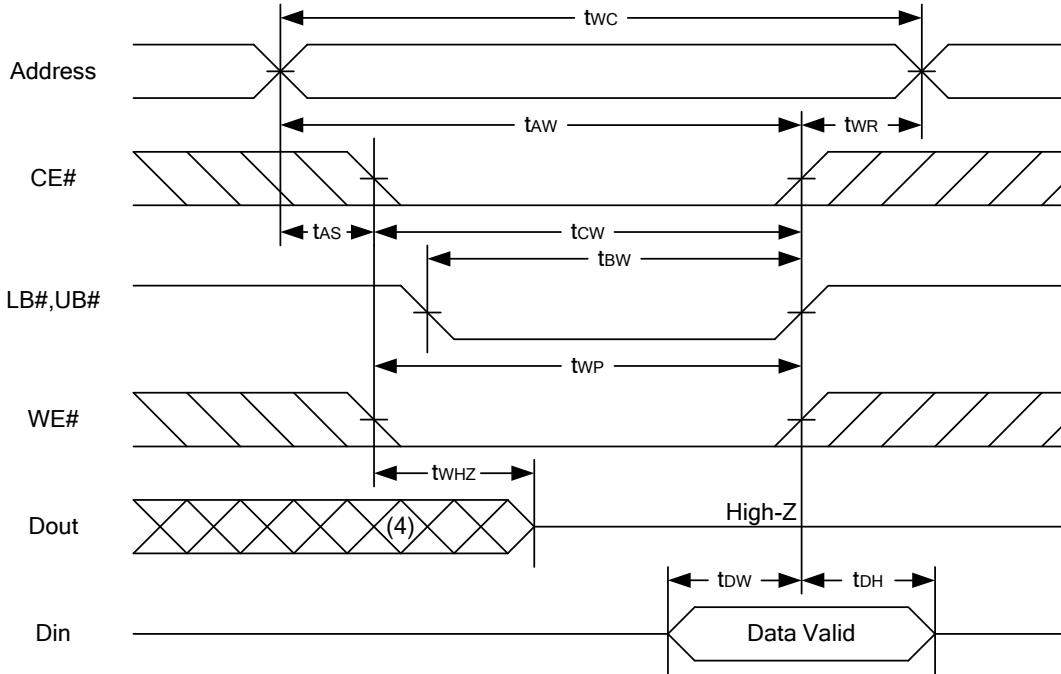


WRITE CYCLE 2 (CE# Controlled) (1,4,5)





WRITE CYCLE 3 (LB#,UB# Controlled) (1,4,5)



Notes :

1. A write occurs during the overlap of a low CE#, low WE#, LB# or UB# = low.
2. During a WE# controlled write cycle with OE# low, t_{WP} must be greater than $t_{WHZ} + t_{DW}$ to allow the drivers to turn off and data to be placed on the bus.
3. During this period, I/O pins are in the output state, and input signals must not be applied.
4. If the CE#, LB#, UB# low transition occurs simultaneously with or after WE# low transition, the outputs remain in a high impedance state.
5. t_{ow} and t_{WHZ} are specified with $C_L = 5pF$. Transition is measured $\pm 500mV$ from steady state.



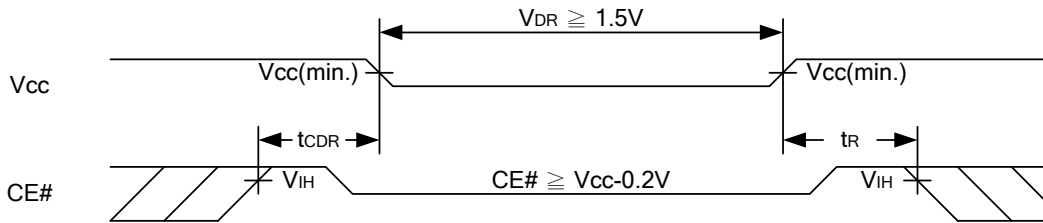
DATA RETENTION CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
V _{CC} for Data Retention	V _{DR}	CE# ≥ V _{CC} - 0.2V	1.5	-	3.6	V
Data Retention Current	I _{DR}	V _{CC} = 1.5V CE# ≥ V _{CC} - 0.2V	LL	-	12	μA
		Others at 0.2V or V _{CC} -0.2V	LLE/LLI	-	16	μA
Chip Disable to Data Retention Time	t _{CDR}	See Data Retention Waveforms (below)	0	-	-	ns
Recovery Time	t _R		t _{RC} *	-	-	ns

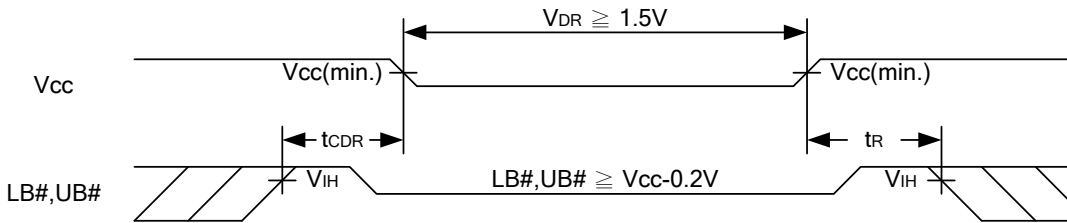
t_{RC}* = Read Cycle Time

DATA RETENTION WAVEFORM

Low V_{CC} Data Retention Waveform (1) (CE# controlled)



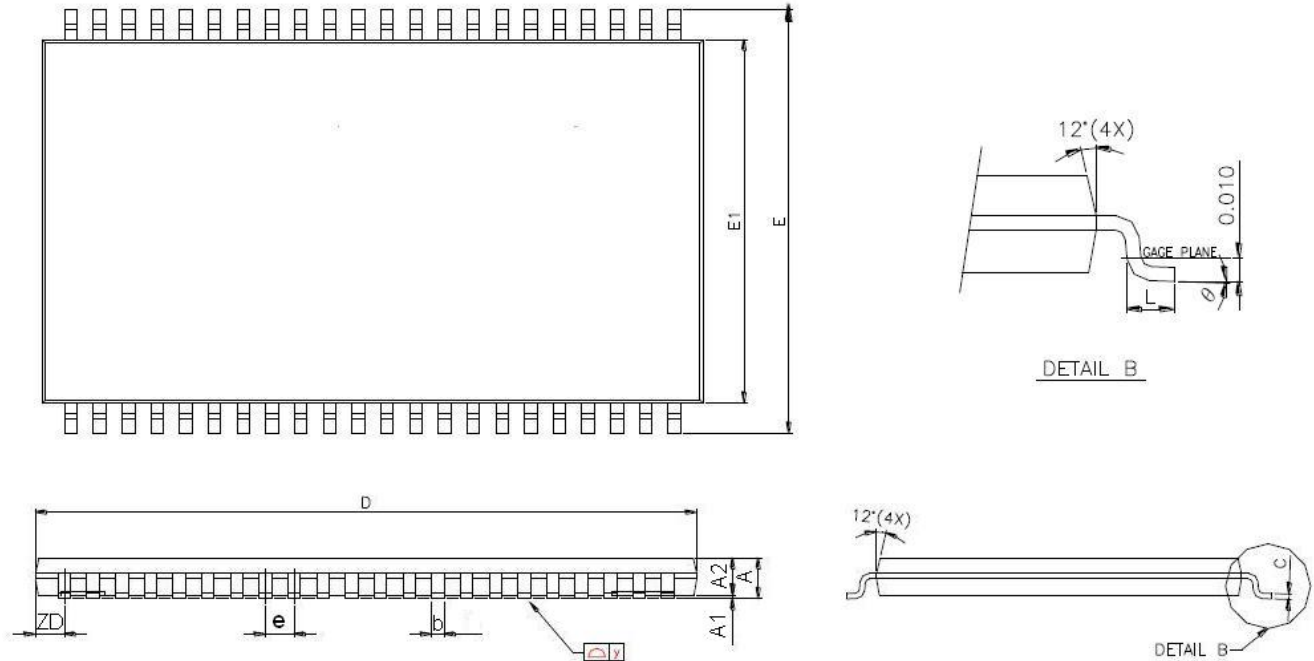
Low V_{CC} Data Retention Waveform (2) (LB#, UB# controlled)





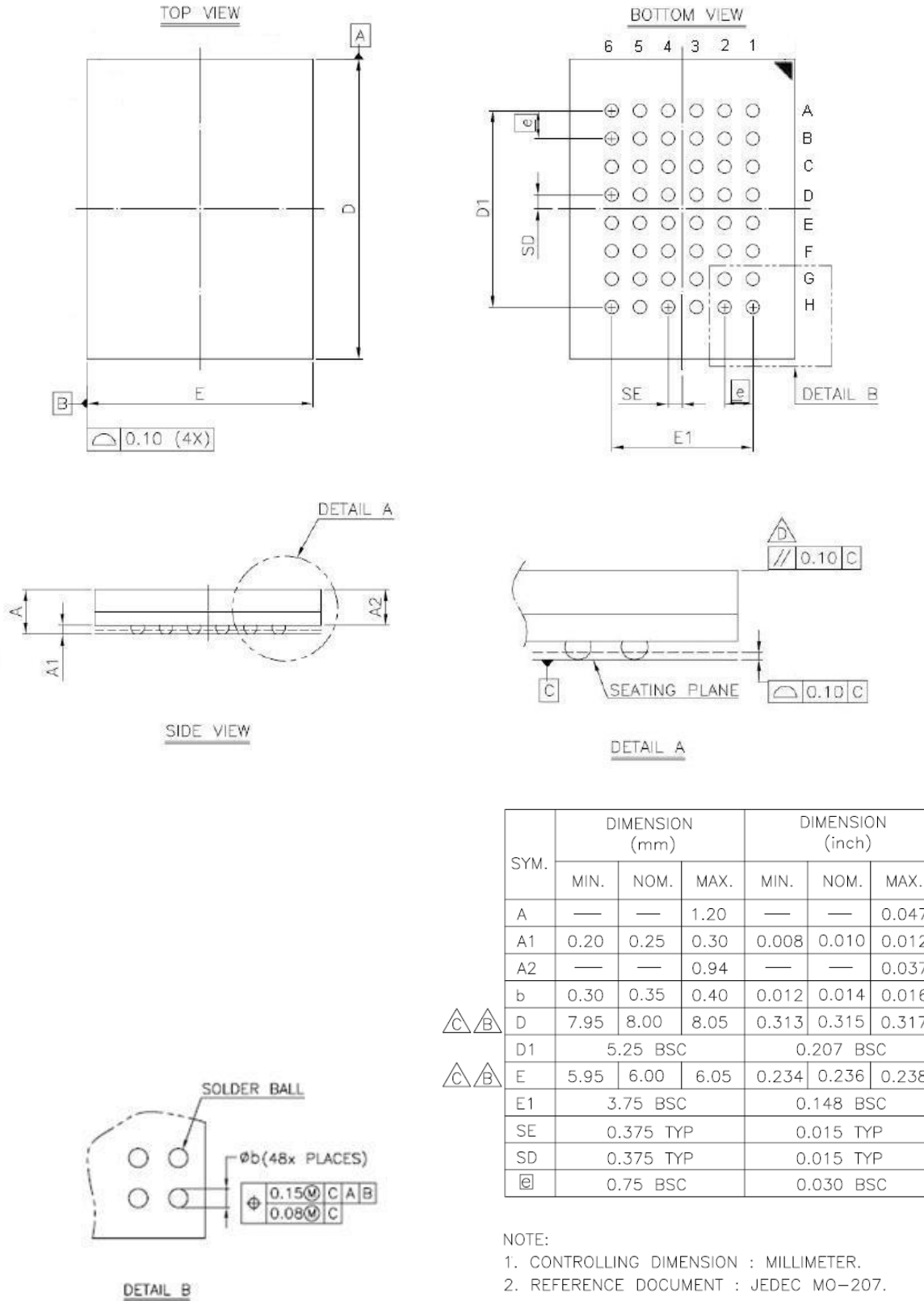
PACKAGE OUTLINE DIMENSION

44-pin 400 mil TSOP II Package Outline Dimension



SYMBOLS	DIMENSIONS IN MILLMETERS			DIMENSIONS IN MILS		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	-	-	1.20	-	-	47.2
A1	0.05	0.10	0.15	2.0	3.9	5.9
A2	0.95	1.00	1.05	37.4	39.4	41.3
b	0.30	-	0.45	11.8	-	17.7
c	0.12	-	0.21	4.7	-	8.3
D	18.212	18.415	18.618	717	725	733
E	11.506	11.760	12.014	453	463	473
E1	9.957	10.160	10.363	392	400	408
e	-	0.800	-	-	31.5	-
L	0.40	0.50	0.60	15.7	19.7	23.6
ZD	-	0.805	-	-	31.7	-
y	-	-	0.076	-	-	3
θ	0°	3°	6°	0°	3°	6°

48-ball 6mm × 8mm TFBGA Package Outline Dimension





ORDERING INFORMATION

[Production Status: M/P]

Package Type	Access Time (Speed)(ns)	Power Type	Temperature Range(°C)	Packing Type	Lyontek Item No.
44-pin (400mil) TSOP II	45	Ultra Low Power	0°C~70°C	Tray	LY62L25616ML-45LL
				Tape Reel	LY62L25616ML-45LLT
			-20°C~80°C	Tray	LY62L25616ML-45LLE
				Tape Reel	LY62L25616ML-45LLET
			-40°C~85°C	Tray	LY62L25616ML-45LLI
				Tape Reel	LY62L25616ML-45LLIT
	55	Ultra Low Power	0°C~70°C	Tray	LY62L25616ML-55LL
				Tape Reel	LY62L25616ML-55LLT
			-20°C~80°C	Tray	LY62L25616ML-55LLE
				Tape Reel	LY62L25616ML-55LLET
			-40°C~85°C	Tray	LY62L25616ML-55LLI
				Tape Reel	LY62L25616ML-55LLIT
70	Ultra Low Power	0°C~70°C	Tray	LY62L25616ML-70LL	
			Tape Reel	LY62L25616ML-70LLT	
		-20°C~80°C	Tray	LY62L25616ML-70LLE	
			Tape Reel	LY62L25616ML-70LLET	
		-40°C~85°C	Tray	LY62L25616ML-70LLI	
			Tape Reel	LY62L25616ML-70LLIT	



ORDERING INFORMATION

[Production Status: M/P]

Package Type	Access Time (Speed)(ns)	Power Type	Temperature Range(°C)	Packing Type	Lyontek Item No.
48-ball (6mm x 8mm) TFBGA	45	Ultra Low Power	0°C~70°C	Tray	LY62L25616GL-45LL
				Tape Reel	LY62L25616GL-45LLT
			-20°C~80°C	Tray	LY62L25616GL-45LLE
				Tape Reel	LY62L25616GL-45LLET
			-40°C~85°C	Tray	LY62L25616GL-45LLI
				Tape Reel	LY62L25616GL-45LLIT
	55	Ultra Low Power	0°C~70°C	Tray	LY62L25616GL-55LL
				Tape Reel	LY62L25616GL-55LLT
			-20°C~80°C	Tray	LY62L25616GL-55LLE
				Tape Reel	LY62L25616GL-55LLET
			-40°C~85°C	Tray	LY62L25616GL-55LLI
				Tape Reel	LY62L25616GL-55LLIT
70	Ultra Low Power	0°C~70°C	Tray	LY62L25616GL-70LL	
			Tape Reel	LY62L25616GL-70LLT	
		-20°C~80°C	Tray	LY62L25616GL-70LLE	
			Tape Reel	LY62L25616GL-70LLET	
		-40°C~85°C	Tray	LY62L25616GL-70LLI	
			Tape Reel	LY62L25616GL-70LLIT	



ORDERING INFORMATION

[Production Status: **EOL**]

Power Type : Special Ultra Low Power

Package Type	Access Time (Speed)(ns)	Temperature Range(°C)	Packing Type	EOL Item No.	Substitute Product
44-pin (400mil) TSOP II	45	0°C~70°C	Tray	LY62L25616ML-45SL	LY62L25616BML-45SL
			Tape Reel	LY62L25616ML-45SLT	LY62L25616BML-45SLT
		-20°C~80°C	Tray	LY62L25616ML-45SLE	LY62L25616BML-45SLI
			Tape Reel	LY62L25616ML-45SLET	LY62L25616BML-45SLIT
		-40°C~85°C	Tray	LY62L25616ML-45SLI	LY62L25616BML-45SLI
			Tape Reel	LY62L25616ML-45SLIT	LY62L25616BML-45SLIT
	55	0°C~70°C	Tray	LY62L25616ML-55SL	LY62L25616BML-45SL
			Tape Reel	LY62L25616ML-55SLT	LY62L25616BML-45SLT
		-20°C~80°C	Tray	LY62L25616ML-55SLE	LY62L25616BML-45SLI
			Tape Reel	LY62L25616ML-55SLET	LY62L25616BML-45SLIT
		-40°C~85°C	Tray	LY62L25616ML-55SLI	LY62L25616ML-45SLI
			Tape Reel	LY62L25616ML-55SLIT	LY62L25616ML-45SLIT
	70	0°C~70°C	Tray	LY62L25616ML-70SL	LY62L25616ML-45SL
			Tape Reel	LY62L25616ML-70SLT	LY62L25616ML-45SLT
		-20°C~80°C	Tray	LY62L25616ML-70SLE	LY62L25616ML-45SLI
			Tape Reel	LY62L25616ML-70SLET	LY62L25616ML-45SLIT
		-40°C~85°C	Tray	LY62L25616ML-70SLI	LY62L25616ML-45SLI
			Tape Reel	LY62L25616ML-70SLIT	LY62L25616ML-45SLIT



ORDERING INFORMATION

[Production Status: **EOL**]

Power Type : Special Ultra Low Power

Package Type	Access Time (Speed)(ns)	Temperature Range(°C)	Packing Type	EOL Item No.	Substitute Product
48-ball (6mm x 8mm) TFBGA	45	0°C~70°C	Tray	LY62L25616GL-45SL	LY62L25616BGL-45SL
			Tape Reel	LY62L25616GL-45SLT	LY62L25616BGL-45SLT
		-20°C~80°C	Tray	LY62L25616GL-45SLE	LY62L25616BGL-45SLI
			Tape Reel	LY62L25616GL-45SLET	LY62L25616BGL-45SLIT
		-40°C~85°C	Tray	LY62L25616GL-45SLI	LY62L25616BGL-45SLI
			Tape Reel	LY62L25616GL-45SLIT	LY62L25616BGL-45SLIT
	55	0°C~70°C	Tray	LY62L25616GL-55SL	LY62L25616BGL-45SL
			Tape Reel	LY62L25616GL-55SLT	LY62L25616BGL-45SLT
		-20°C~80°C	Tray	LY62L25616GL-55SLE	LY62L25616BGL-45SLI
			Tape Reel	LY62L25616GL-55SLET	LY62L25616BGL-45SLIT
		-40°C~85°C	Tray	LY62L25616GL-55SLI	LY62L25616BGL-45SLI
			Tape Reel	LY62L25616GL-55SLIT	LY62L25616BGL-45SLIT
	70	0°C~70°C	Tray	LY62L25616GL-70SL	LY62L25616BGL-45SL
			Tape Reel	LY62L25616GL-70SLT	LY62L25616BGL-45SLT
		-20°C~80°C	Tray	LY62L25616GL-70SLE	LY62L25616BGL-45SLI
			Tape Reel	LY62L25616GL-70SLET	LY62L25616BGL-45SLIT
		-40°C~85°C	Tray	LY62L25616GL-70SLI	LY62L25616BGL-45SLI
			Tape Reel	LY62L25616GL-70SLIT	LY62L25616BGL-45SLIT



Lyontek Inc.

LY62L25616

Rev. 3.0

256K X 16 BIT LOW POWER CMOS SRAM

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